

XP132A1275SR

TOREX

ETR1108_001

Power MOSFET

■GENERAL DESCRIPTION

The XP132A1275SR is a P-channel Power MOSFET with low on-state resistance and ultra high-speed switching characteristics.

Because high-speed switching is possible, the IC can be efficiently set thereby saving energy.

The small SOP-8 package makes high density mounting possible.

■APPLICATIONS

- Notebook PCs
- Cellular and portable phones
- On-board power supplies
- Li-ion battery systems

■FEATURES

Low On-State Resistance : $R_{ds(on)}=0.075\Omega$ ($V_{gs}=-4.5V$)
: $R_{ds(on)}=0.115\Omega$ ($V_{gs}=-2.5V$)

Ultra High-Speed Switching

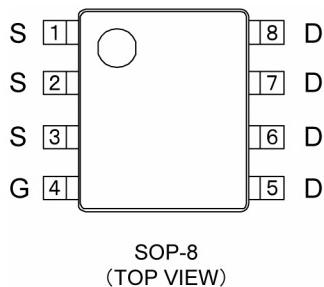
Driving Voltage : -2.5V

P-Channel Power MOSFET

DMOS Structure

Package : SOP-8

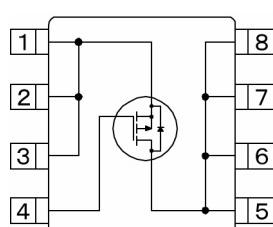
■PIN CONFIGURATION



■PIN ASSIGNMENT

PIN NUMBER	PIN NAME	FUNCTION
1~3	S	Source
4	G	Gate
5~8	D	Drain

■EQUIVALENT CIRCUIT



P-channel MOSFET
(1 device built-in)

■ABSOLUTE MAXIMUM RATINGS

$T_a = 25^\circ C$

PARAMETER	SYMBOL	RATINGS	UNITS
Drain-Source Voltage	V_{dss}	-20	V
Gate-Source Voltage	V_{gss}	± 12	V
Drain Current (DC)	I_d	-5	A
Drain Current (Pulse)	I_{dp}	-20	A
Reverse Drain Current	I_{dr}	-5	A
Channel Power Dissipation *	P_d	2.5	W
Channel Temperature	T_{ch}	150	°C
Storage Temperature Range	T_{stg}	-55~150	°C

* When implemented on a glass epoxy PCB

■ ELECTRICAL CHARACTERISTICS

DC Characteristics

T_a = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Drain Cut-Off Current	Idss	V _{ds} =-20V, V _{gs} =0V	-	-	-10	μA
Gate-Source Leak Current	I _{gss}	V _{gs} =±12V, V _{ds} =0V	-	-	±1	μA
Gate-Source Cut-Off Voltage	V _{gs(off)}	I _d =-1mA, V _{ds} =-10V	-0.5	-	-1.2	V
Drain-Source On-State Resistance *	R _{ds(on)}	I _d =-3A, V _{gs} =-4.5V	-	0.06	0.075	Ω
		I _d =-3A, V _{gs} =-2.5V	-	0.092	0.115	Ω
Forward Transfer Admittance *	Y _{fs}	I _d =-3A, V _{ds} =-10V	-	8	-	S
Body Drain Diode Forward Voltage	V _f	I _f =-5A, V _{gs} =0V	-	-0.85	-1.1	V

* Effective during pulse test.

Dynamic Characteristics

T_a = 25°C

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Capacitance	C _{iss}	V _{ds} =-10V, V _{gs} =0V f=1MHz	-	770	-	pF
Output Capacitance	C _{oss}		-	440	-	pF
Feedback Capacitance	C _{rss}		-	180	-	pF

Switching Characteristics

T_a = 25°C

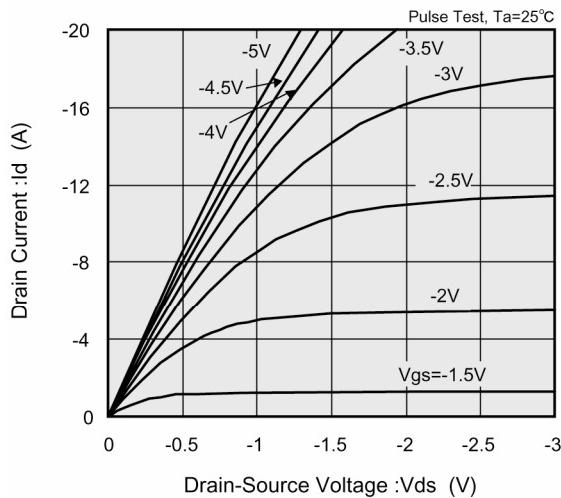
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-On Delay Time	t _d (on)	V _{gs} =-5V, I _d =-3A V _{dd} =-10V	-	10	-	ns
Rise Time	t _r		-	25	-	ns
Turn-Off Delay Time	t _d (off)		-	45	-	ns
Fall Time	t _f		-	40	-	ns

Thermal Characteristics

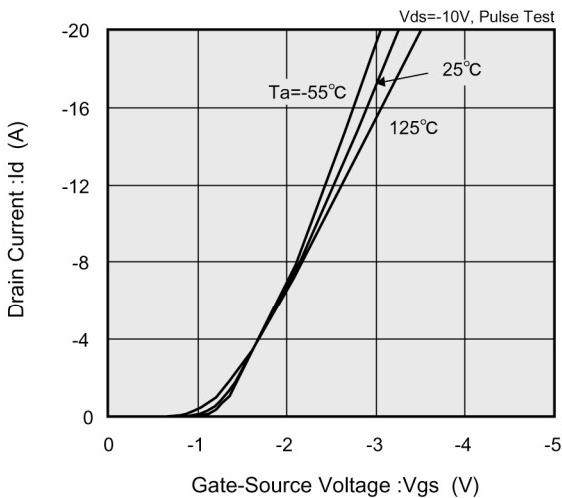
PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal Resistance (Channel-Ambience)	R _{th} (ch-a)	Implement on a glass epoxy resin PCB	-	50	-	°C/W

■ TYPICAL PERFORMANCE CHARACTERISTICS

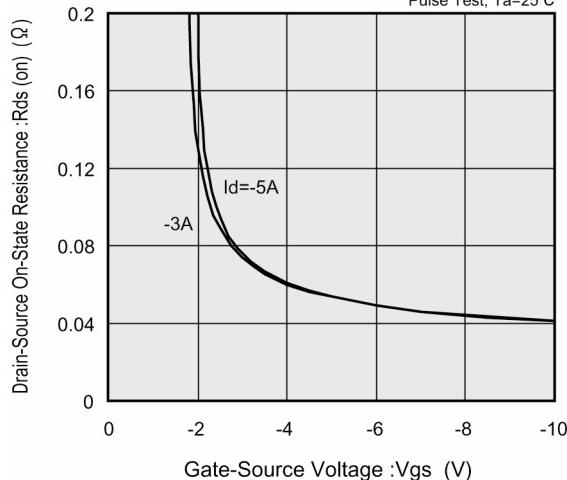
(1) Drain Current vs. Drain-Source Voltage



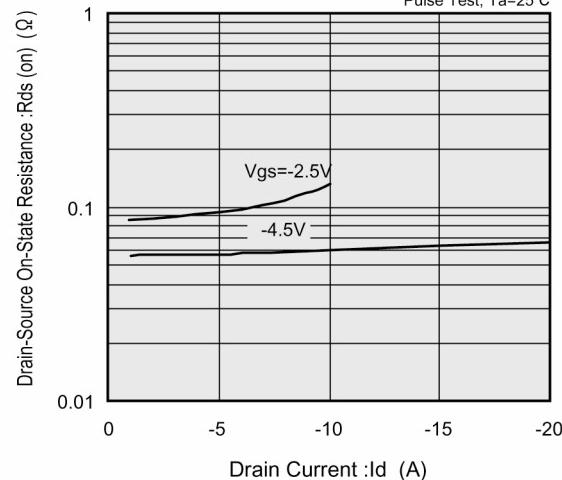
(2) Drain Current vs. Gate-Source Voltage



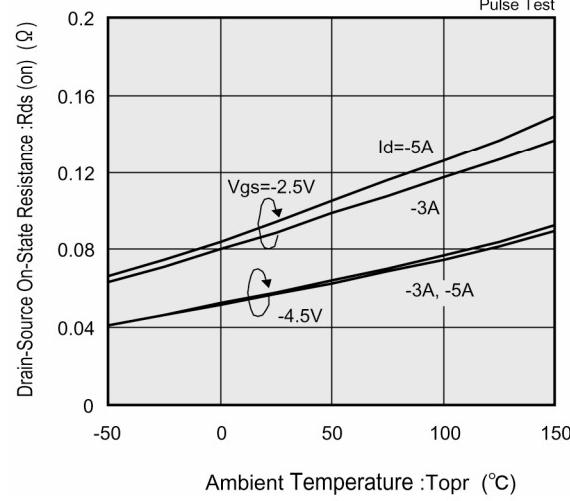
(3) Drain-Source On-State Resistance vs. Gate-Source Voltage



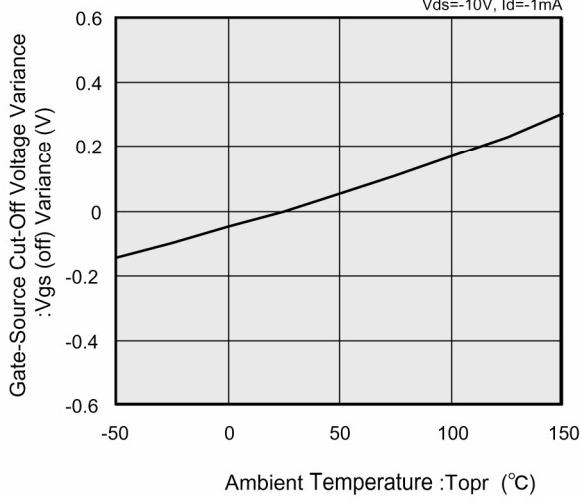
(4) Drain-Source On-State Resistance vs. Drain Current



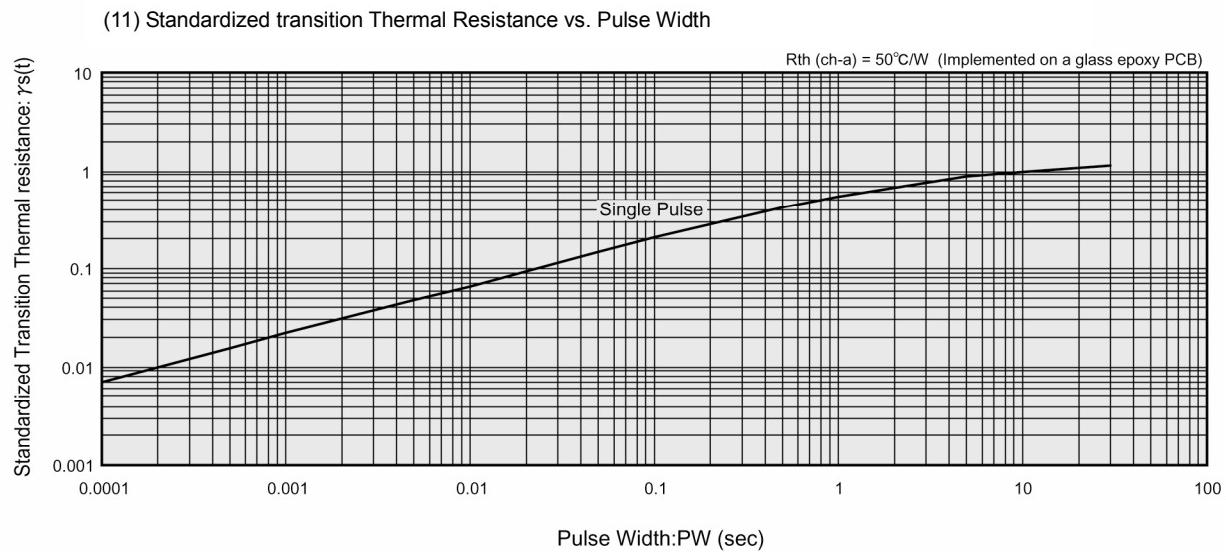
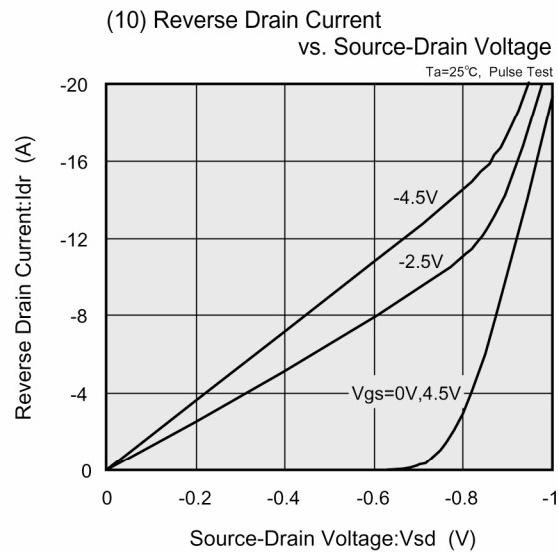
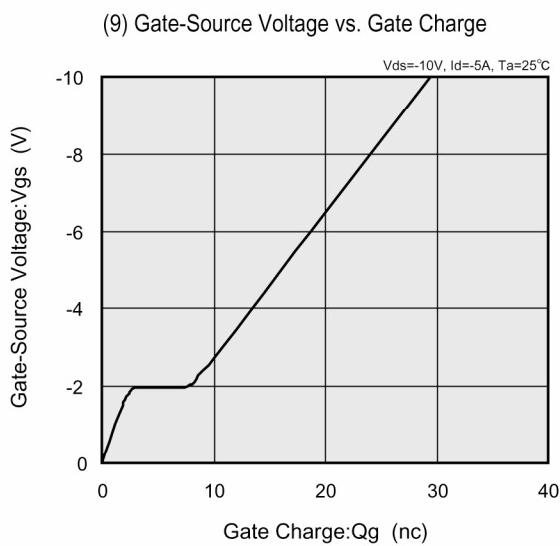
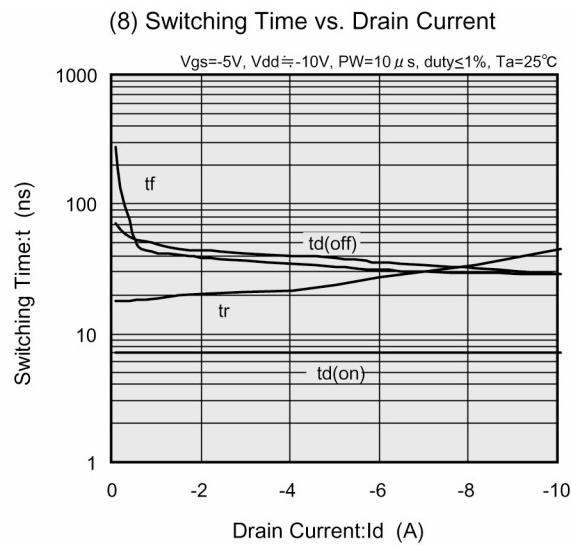
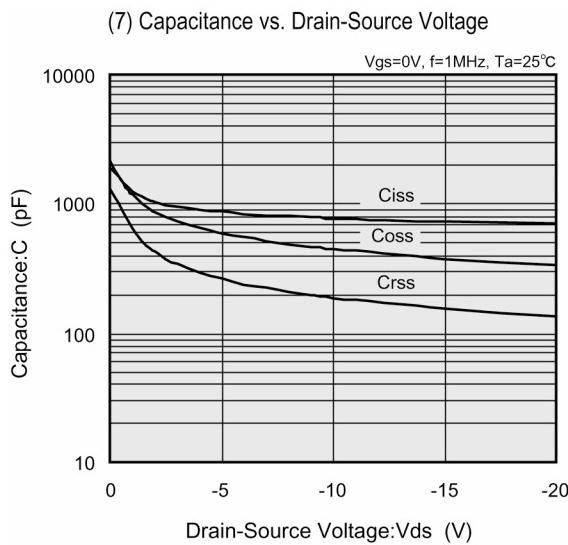
(5) Drain-Source On-State Resistance vs. Ambient Temperature



(6) Gate-Source Cut-Off Voltage Variance vs. Ambient Temperature



■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)



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